Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-242-3306

Inclosure Material: Ceramic Function For Which Designed: Impatt diode **End Application:** An/apm-427 **Features Provided:** Hermetically sealed case and burn in Semiconductor Material: Gallium arsenide Voltage Rating In Volts Per Characteristic: 48.0 breakdown voltage, instantaneous Shelf Life: N/a Unit Of Measure: ---**Demilitarization:** Yes - demil/mli

Fiig:

A110a0